



# STB5NK50Z/-1 - STD5NK50Z/-1 STP5NK50Z - STP5NK50ZFP

N-CHANNEL 500V - 1.22Ω - 4.4A TO-220/FP-D/IPAK-D<sup>2</sup>/I<sup>2</sup>PAK  
Zener-Protected SuperMESH™ MOSFET

**Table 1: General Features**

| TYPE        | V <sub>DSS</sub> | R <sub>DS(on)</sub> | I <sub>D</sub> | P <sub>w</sub> |
|-------------|------------------|---------------------|----------------|----------------|
| STB5NK50Z   | 500 V            | < 1.5 Ω             | 4.4 A          | 70 W           |
| STB5NK50Z-1 | 500 V            | < 1.5 Ω             | 4.4 A          | 70 W           |
| STD5NK50Z   | 500 V            | < 1.5 Ω             | 4.4 A          | 70 W           |
| STD5NK50Z-1 | 500 V            | < 1.5 Ω             | 4.4 A          | 70 W           |
| STP5K50Z    | 500 V            | < 1.5 Ω             | 4.4 A          | 70 W           |
| STP5K50ZFP  | 500 V            | < 1.5 Ω             | 4.4 A          | 25 W           |

- TYPICAL R<sub>DS(on)</sub> = 1.22 Ω
- EXTREMELY HIGH dv/dt CAPABILITY
- IMPROVED ESD CAPABILITY
- 100% AVALANCHE RATED
- GATE CHARGE MINIMIZED
- VERY LOW INTRINSIC CAPACITANCES
- VERY GOOD MANUFACTURING REPEATABILITY

## DESCRIPTION

The SuperMESH™ series is obtained through an extreme optimization of ST's well established striptbased PowerMESH™ layout. In addition to pushing on-resistance significantly down, special care is taken to ensure a very good dv/dt capability for the most demanding applications. Such series complements ST full range of high voltage MOSFETs including revolutionary MDmesh™ products.

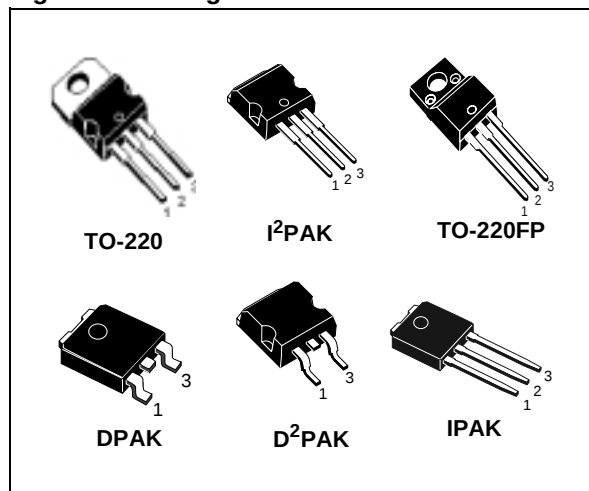
## APPLICATIONS

- HIGH CURRENT, HIGH SPEED SWITCHING
- IDEAL FOR OFF-LINE POWER SUPPLIES, ADAPTORS AND PFC
- LIGHTING

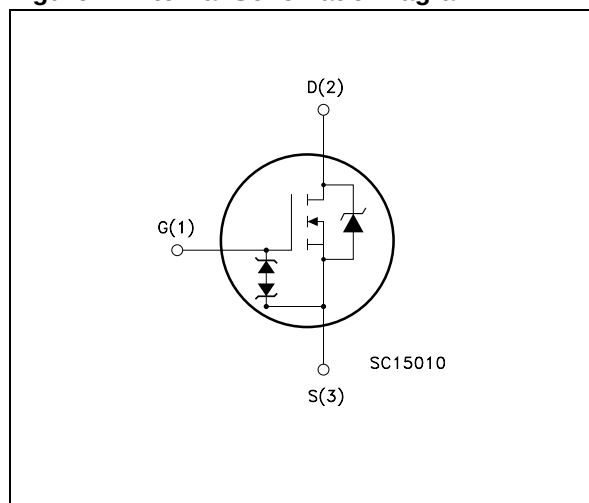
**Table 2: Order Codes**

| SALES TYPE  | MARKING   | PACKAGE            | PACKAGING   |
|-------------|-----------|--------------------|-------------|
| STB5NK50ZT4 | B5NK50Z   | D <sup>2</sup> PAK | TAPE & REEL |
| STB5NK50Z-1 | B5NK50Z   | I <sup>2</sup> PAK | TUBE        |
| STD5NK50ZT4 | D5NK50Z   | DPAK               | TAPE & REEL |
| STD5NK50Z-1 | D5NK50Z   | IPAK               | TUBE        |
| STP5NK50Z   | P5NK50Z   | TO-220             | TUBE        |
| STP5NK50ZFP | P5NK50ZFP | TO-220FP           | TUBE        |

**Figure 1: Package**



**Figure 2: Internal Schematic Diagram**



**Table 3: Absolute Maximum ratings**

| Symbol                             | Parameter                                             | Value                     |             |                          | Unit     |
|------------------------------------|-------------------------------------------------------|---------------------------|-------------|--------------------------|----------|
|                                    |                                                       | STP5NK50Z<br>STB5NK50Z/-1 | STP5NK50ZFP | STD5NK50Z<br>STD5NK50Z-1 |          |
| V <sub>DS</sub>                    | Drain-source Voltage (V <sub>GS</sub> = 0)            | 500                       |             |                          | V        |
| V <sub>DGR</sub>                   | Drain-gate Voltage (R <sub>GS</sub> = 20 kΩ)          | 500                       |             |                          | V        |
| V <sub>GS</sub>                    | Gate- source Voltage                                  | ± 30                      |             |                          | V        |
| I <sub>D</sub>                     | Drain Current (continuous) at T <sub>C</sub> = 25°C   | 4.4                       | 4.4 (*)     | 4.4                      | A        |
| I <sub>D</sub>                     | Drain Current (continuous) at T <sub>C</sub> = 100°C  | 2.7                       | 2.7 (*)     | 2.7                      | A        |
| I <sub>DM</sub> (•)                | Drain Current (pulsed)                                | 17.6                      | 17.6 (*)    | 17.6                     | A        |
| P <sub>TOT</sub>                   | Total Dissipation at T <sub>C</sub> = 25°C            | 70                        | 25          | 70                       | W        |
|                                    | Derating Factor                                       | 0.56                      | 0.2         | 0.56                     | W/°C     |
| V <sub>ESD(G-S)</sub>              | Gate source ESD(HBM-C=100pF, R=1.5KΩ)                 | 3000                      |             |                          | V        |
| dv/dt (1)                          | Peak Diode Recovery voltage slope                     | 4.5                       |             |                          | V/ns     |
| V <sub>ISO</sub>                   | Insulation Withstand Voltage (DC)                     | -                         | 2500        | -                        | V        |
| T <sub>j</sub><br>T <sub>stg</sub> | Operating Junction Temperature<br>Storage Temperature | -55 to 150<br>-55 to 150  |             |                          | °C<br>°C |

(•) Pulse width limited by safe operating area

(1) I<sub>SD</sub> ≤ 4.4A, di/dt ≤ 200A/μs, V<sub>DD</sub> ≤ V<sub>(BR)DSS</sub>, T<sub>j</sub> ≤ T<sub>JMAX</sub>.

(\*) Limited only by maximum temperature allowed

**Table 4: Thermal Data**

|                       |                                                | TO-220<br>I <sup>2</sup> PAK/D <sup>2</sup> PAK | TO-220FP | DPAK |      |
|-----------------------|------------------------------------------------|-------------------------------------------------|----------|------|------|
| R <sub>thj-case</sub> | Thermal Resistance Junction-case Max           | 1.78                                            | 5        | 1.78 | °C/W |
| R <sub>thj-amb</sub>  | Thermal Resistance Junction-ambient Max        | 62.5                                            |          |      | °C/W |
| T <sub>I</sub>        | Maximum Lead Temperature For Soldering Purpose | 300                                             |          |      | °C   |

**Table 5: Avalanche Characteristics**

| Symbol          | Parameter                                                                                                                     | Max Value | Unit |
|-----------------|-------------------------------------------------------------------------------------------------------------------------------|-----------|------|
| I <sub>AR</sub> | Avalanche Current, Repetitive or Not-Repetitive<br>(pulse width limited by T <sub>j</sub> max)                                | 4.4       | A    |
| E <sub>AS</sub> | Single Pulse Avalanche Energy<br>(starting T <sub>j</sub> = 25 °C, I <sub>D</sub> = I <sub>AR</sub> , V <sub>DD</sub> = 50 V) | 130       | mJ   |

**Table 6: Gate-Source Zener Diode**

| Symbol            | Parameter                     | Test Conditions                     | Min. | Typ. | Max. | Unit |
|-------------------|-------------------------------|-------------------------------------|------|------|------|------|
| BV <sub>GSO</sub> | Gate-Source Breakdown Voltage | I <sub>GS</sub> =± 1mA (Open Drain) | 30   |      |      | V    |

## PROTECTION FEATURES OF GATE-TO-SOURCE ZENER DIODES

The built-in back-to-back Zener diodes have specifically been designed to enhance not only the device's ESD capability, but also to make them safely absorb possible voltage transients that may occasionally be applied from gate to source. In this respect the Zener voltage is appropriate to achieve an efficient and cost-effective intervention to protect the device's integrity. These integrated Zener diodes thus avoid the usage of external components.

**ELECTRICAL CHARACTERISTICS** ( $T_{CASE} = 25^{\circ}\text{C}$  UNLESS OTHERWISE SPECIFIED)**Table 7: On /Off**

| Symbol        | Parameter                                        | Test Conditions                                                                            | Min. | Typ. | Max.     | Unit                           |
|---------------|--------------------------------------------------|--------------------------------------------------------------------------------------------|------|------|----------|--------------------------------|
| $V_{(BR)DSS}$ | Drain-source Breakdown Voltage                   | $I_D = 1\text{ mA}$ , $V_{GS} = 0$                                                         | 500  |      |          | V                              |
| $I_{DSS}$     | Zero Gate Voltage Drain Current ( $V_{GS} = 0$ ) | $V_{DS} = \text{Max Rating}$<br>$V_{DS} = \text{Max Rating}$ , $T_C = 125^{\circ}\text{C}$ |      |      | 1<br>50  | $\mu\text{A}$<br>$\mu\text{A}$ |
| $I_{GSS}$     | Gate-body Leakage Current ( $V_{DS} = 0$ )       | $V_{GS} = \pm 20\text{ V}$                                                                 |      |      | $\pm 10$ | $\mu\text{A}$                  |
| $V_{GS(th)}$  | Gate Threshold Voltage                           | $V_{DS} = V_{GS}$ , $I_D = 50\text{ }\mu\text{A}$                                          | 3    | 3.75 | 4.5      | V                              |
| $R_{DS(on)}$  | Static Drain-source On Resistance                | $V_{GS} = 10\text{ V}$ , $I_D = 2.2\text{ A}$                                              |      | 1.22 | 1.5      | $\Omega$                       |

**Table 8: Dynamic**

| Symbol                                        | Parameter                                                               | Test Conditions                                                                                                           | Min. | Typ.                 | Max. | Unit                 |
|-----------------------------------------------|-------------------------------------------------------------------------|---------------------------------------------------------------------------------------------------------------------------|------|----------------------|------|----------------------|
| $g_{fs}$ (1)                                  | Forward Transconductance                                                | $V_{DS} = 15\text{ V}$ , $I_D = 2.2\text{ A}$                                                                             |      | 3.1                  |      | S                    |
| $C_{iss}$<br>$C_{oss}$<br>$C_{rss}$           | Input Capacitance<br>Output Capacitance<br>Reverse Transfer Capacitance | $V_{DS} = 25\text{ V}$ , $f = 1\text{ MHz}$ , $V_{GS} = 0$                                                                |      | 535<br>75<br>17      |      | pF<br>pF<br>pF       |
| $C_{OSS\text{ eq}}$ (3)                       | Equivalent Output Capacitance                                           | $V_{GS} = 0\text{ V}$ , $V_{DS} = 0\text{ to }400\text{ V}$                                                               |      | 45                   |      | pF                   |
| $t_{d(on)}$<br>$t_r$<br>$t_{d(off)}$<br>$t_f$ | Turn-on Delay Time<br>Rise Time<br>Turn-off-Delay Time<br>Fall Time     | $V_{DD} = 250\text{ V}$ , $I_D = 2.2\text{ A}$ ,<br>$R_G = 4.7\text{ }\Omega$ , $V_{GS} = 10\text{ V}$<br>(see Figure 19) |      | 15<br>10<br>32<br>15 |      | ns<br>ns<br>ns<br>ns |
| $Q_g$<br>$Q_{gs}$<br>$Q_{gd}$                 | Total Gate Charge<br>Gate-Source Charge<br>Gate-Drain Charge            | $V_{DD} = 400\text{ V}$ , $I_D = 4.4\text{ A}$ ,<br>$V_{GS} = 10\text{ V}$<br>(see Figure 22)                             |      | 20<br>4<br>10        | 28   | nC<br>nC<br>nC       |

**Table 9: Source Drain Diode**

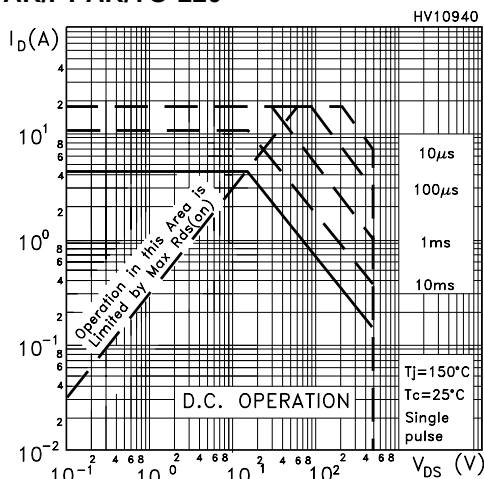
| Symbol                            | Parameter                                                                    | Test Conditions                                                                                                                         | Min. | Typ.               | Max.        | Unit          |
|-----------------------------------|------------------------------------------------------------------------------|-----------------------------------------------------------------------------------------------------------------------------------------|------|--------------------|-------------|---------------|
| $I_{SD}$<br>$I_{SDM}$ (2)         | Source-drain Current<br>Source-drain Current (pulsed)                        |                                                                                                                                         |      |                    | 4.4<br>17.6 | A<br>A        |
| $V_{SD}$ (1)                      | Forward On Voltage                                                           | $I_{SD} = 4.4\text{ A}$ , $V_{GS} = 0$                                                                                                  |      |                    | 1.6         | V             |
| $t_{rr}$<br>$Q_{rr}$<br>$I_{RRM}$ | Reverse Recovery Time<br>Reverse Recovery Charge<br>Reverse Recovery Current | $I_{SD} = 4.4\text{ A}$ , $di/dt = 100\text{ A}/\mu\text{s}$<br>$V_{DD} = 30\text{ V}$ , $T_j = 150^{\circ}\text{C}$<br>(see Figure 20) |      | 310<br>1425<br>9.2 |             | ns<br>nC<br>A |

(1) Pulsed: Pulse duration = 300  $\mu\text{s}$ , duty cycle 1.5 %.

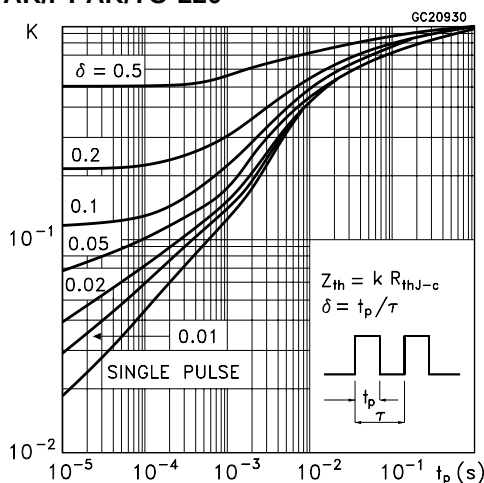
(2) Pulse width limited by safe operating area.

(3)  $C_{OSS\text{ eq}}$  is defined as a constant equivalent capacitance giving the same charging time as  $C_{OSS}$  when  $V_{DS}$  increases from 0 to 80%  $V_{DSS}$ .

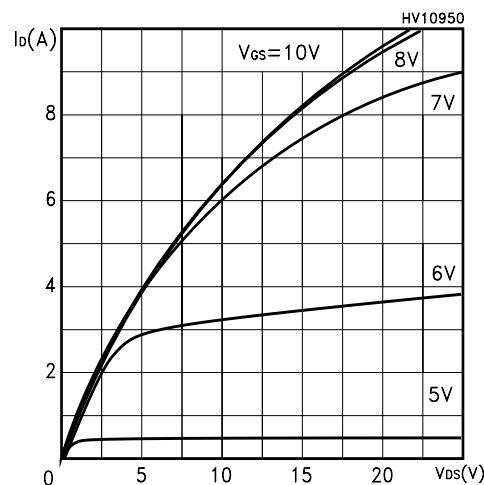
**Figure 3: Safe Operating Area For DPAK/IPAK/  
D<sup>2</sup>PAK/I<sup>2</sup>PAK/TO-220**



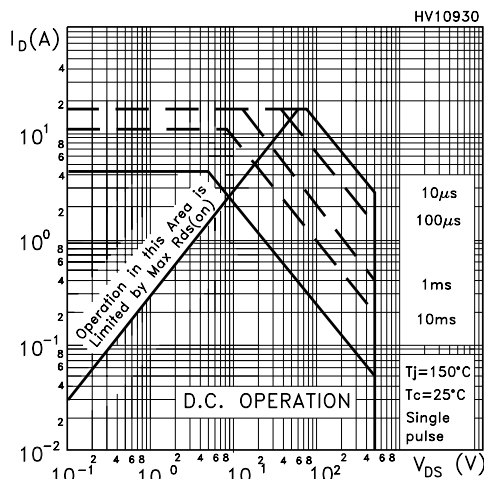
**Figure 4: Thermal Impedance For DPAK/IPAK/  
D<sup>2</sup>PAK/I<sup>2</sup>PAK/TO-220**



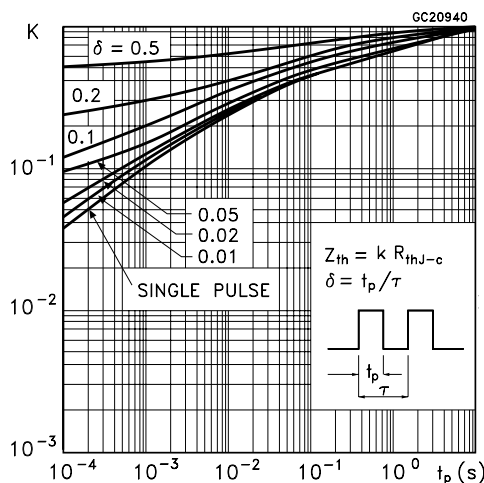
**Figure 5: Output Characteristics**



**Figure 6: Safe Operating Area For TO-220FP**



**Figure 7: Thermal Impedance For TO-220FP**



**Figure 8: Transfer Characteristics**

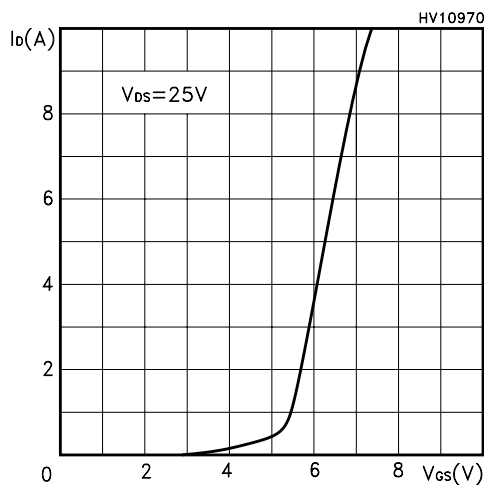


Figure 9: Transconductance

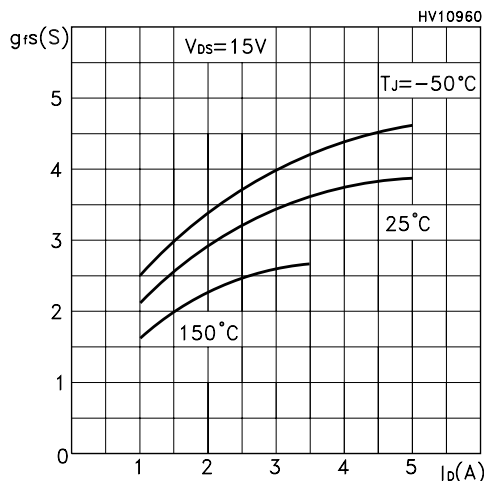


Figure 10: Gate Charge vs Gate-source Voltage

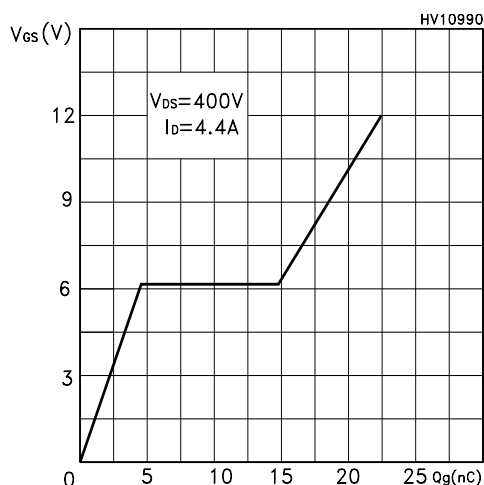


Figure 11: Normalized Gate Threshold Voltage vs Temperature

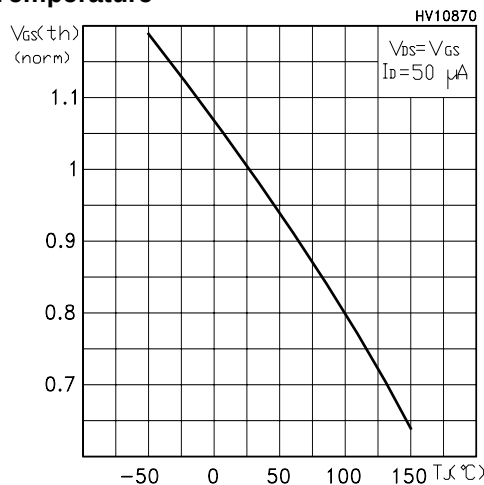


Figure 12: Static Drain-Source On Resistance

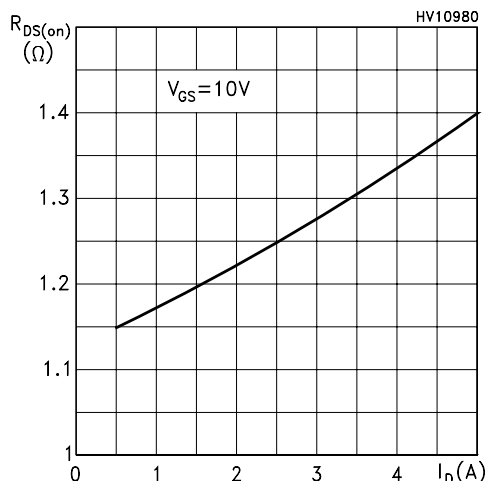


Figure 13: Capacitance Variations

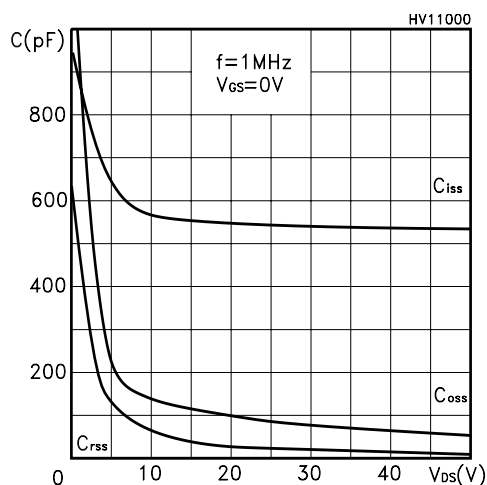


Figure 14: Normalized On Resistance vs Temperature

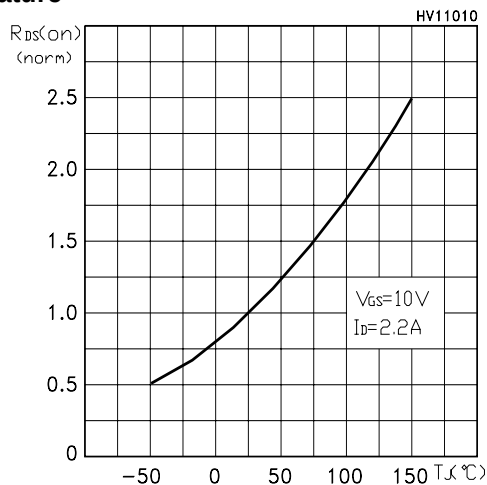


Figure 15: Source-Drain Forward Characteristics

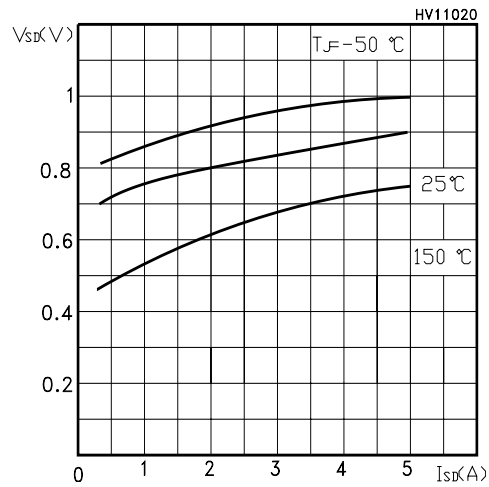


Figure 16: Maximum Avalanche Energy vs Temperature

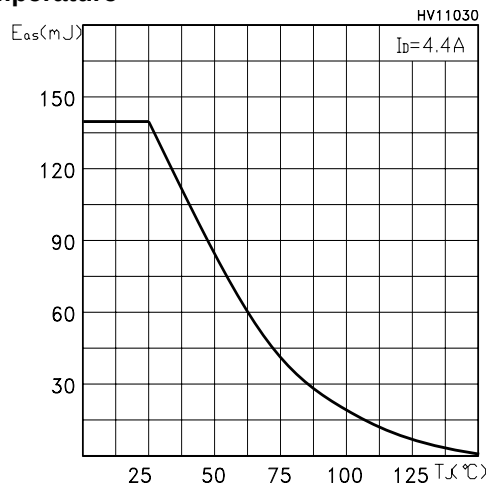
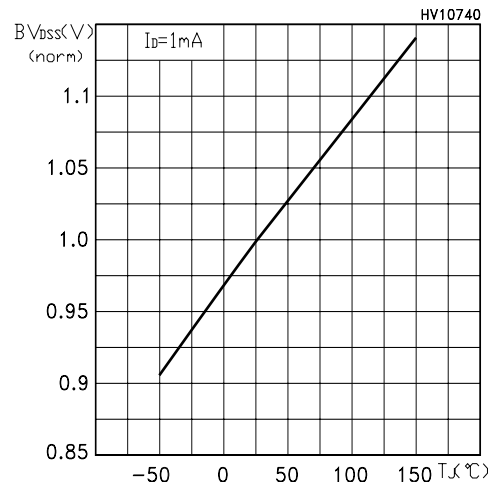
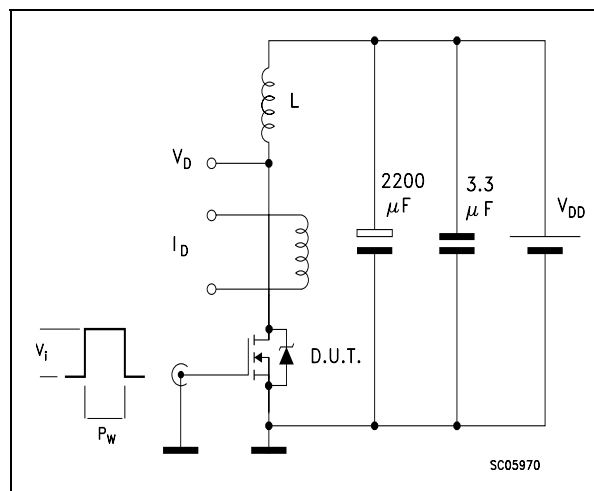


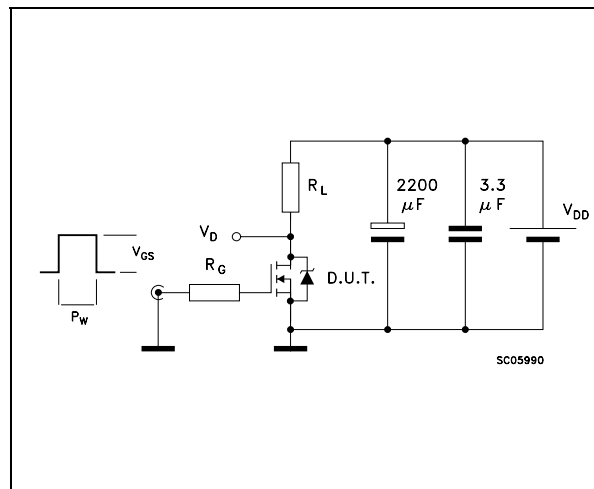
Figure 17: Normalized  $BV_{DSS}$  vs Temperature



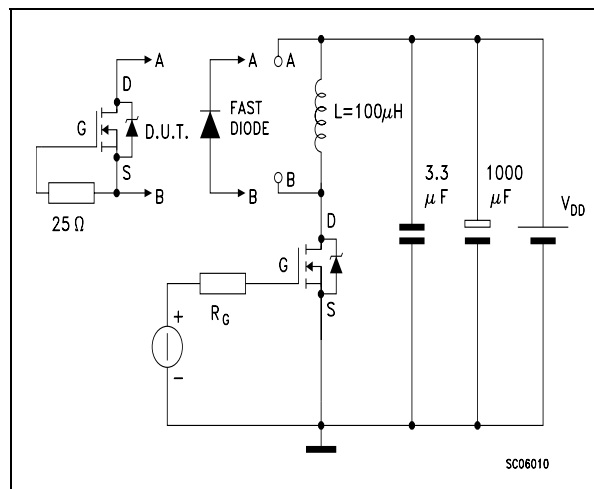
**Figure 18: Unclamped Inductive Load Test Circuit**



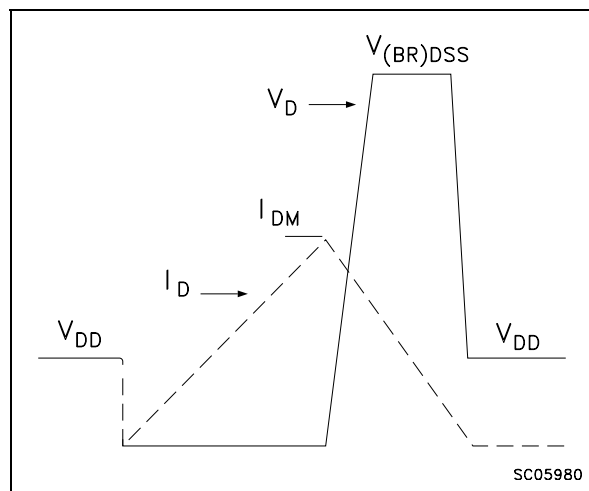
**Figure 19: Switching Times Test Circuit For Resistive Load**



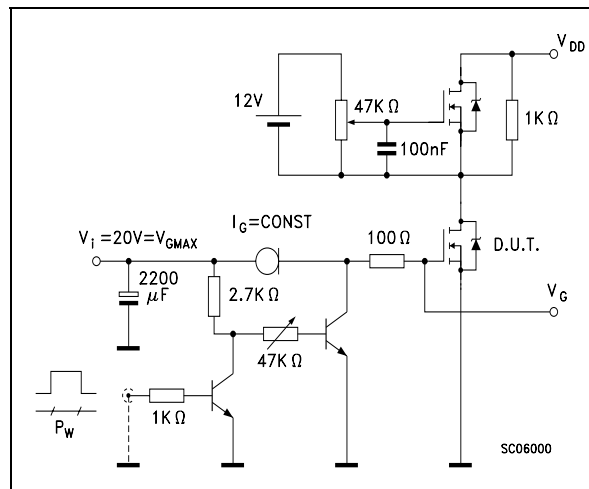
**Figure 20: Test Circuit For Inductive Load Switching and Diode Recovery Times**



**Figure 21: Unclamped Inductive Waform**



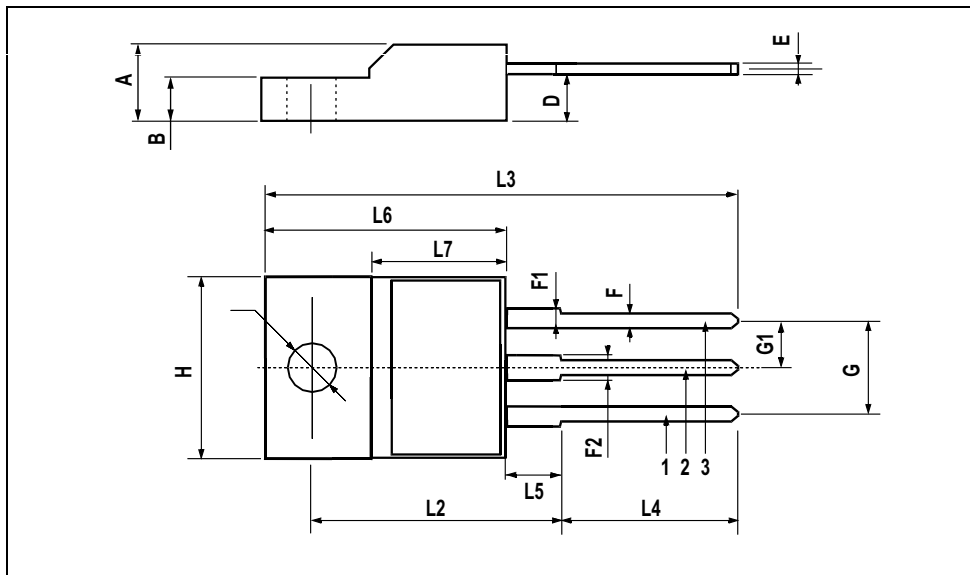
**Figure 22: Gate Charge Test Circuit**



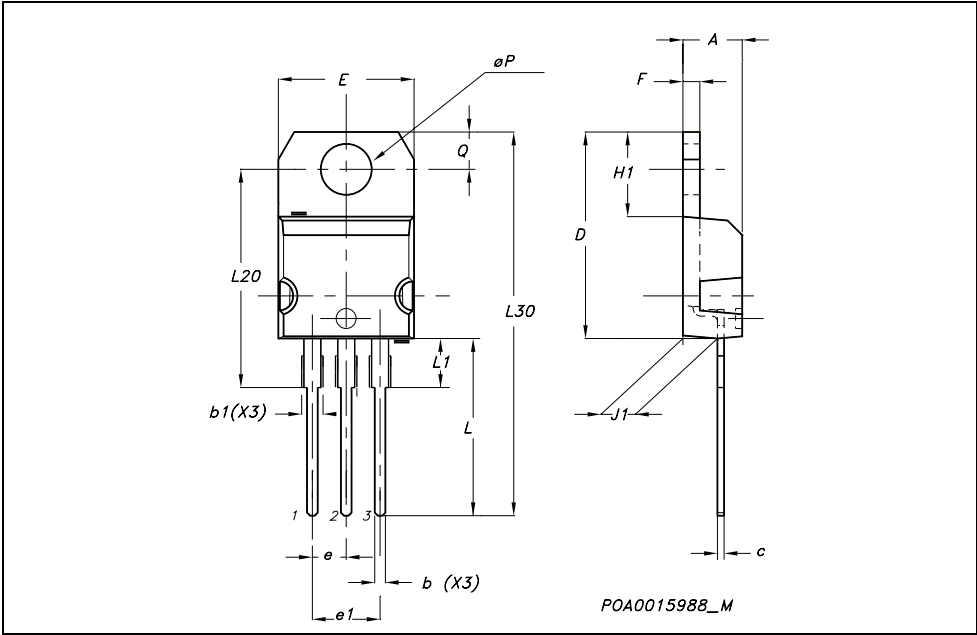
In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect . The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: [www.st.com](http://www.st.com)

## TO-220FP MECHANICAL DATA

| DIM. | mm.  |      |      | inch  |       |       |
|------|------|------|------|-------|-------|-------|
|      | MIN. | TYP. | MAX. | MIN.  | TYP.  | MAX.  |
| A    | 4.4  |      | 4.6  | 0.173 |       | 0.181 |
| B    | 2.5  |      | 2.7  | 0.098 |       | 0.106 |
| D    | 2.5  |      | 2.75 | 0.098 |       | 0.108 |
| E    | 0.45 |      | 0.7  | 0.017 |       | 0.027 |
| F    | 0.75 |      | 1    | 0.030 |       | 0.039 |
| F1   | 1.15 |      | 1.7  | 0.045 |       | 0.067 |
| F2   | 1.15 |      | 1.7  | 0.045 |       | 0.067 |
| G    | 4.95 |      | 5.2  | 0.195 |       | 0.204 |
| G1   | 2.4  |      | 2.7  | 0.094 |       | 0.106 |
| H    | 10   |      | 10.4 | 0.393 |       | 0.409 |
| L2   |      | 16   |      |       | 0.630 |       |
| L3   | 28.6 |      | 30.6 | 1.126 |       | 1.204 |
| L4   | 9.8  |      | 10.6 | .0385 |       | 0.417 |
| L5   | 2.9  |      | 3.6  | 0.114 |       | 0.141 |
| L6   | 15.9 |      | 16.4 | 0.626 |       | 0.645 |
| L7   | 9    |      | 9.3  | 0.354 |       | 0.366 |
| Ø    | 3    |      | 3.2  | 0.118 |       | 0.126 |

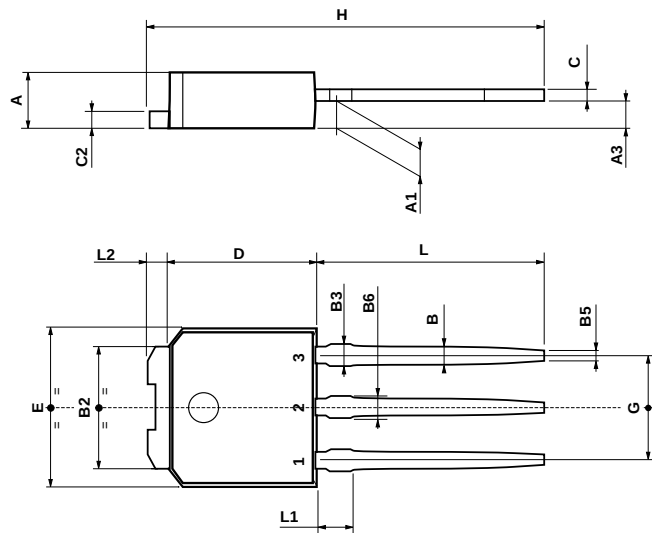


| TO-220 MECHANICAL DATA |       |       |       |       |       |       |
|------------------------|-------|-------|-------|-------|-------|-------|
| DIM.                   | mm.   |       |       | inch  |       |       |
|                        | MIN.  | TYP   | MAX.  | MIN.  | TYP.  | MAX.  |
| A                      | 4.40  |       | 4.60  | 0.173 |       | 0.181 |
| b                      | 0.61  |       | 0.88  | 0.024 |       | 0.034 |
| b1                     | 1.15  |       | 1.70  | 0.045 |       | 0.066 |
| c                      | 0.49  |       | 0.70  | 0.019 |       | 0.027 |
| D                      | 15.25 |       | 15.75 | 0.60  |       | 0.620 |
| E                      | 10    |       | 10.40 | 0.393 |       | 0.409 |
| e                      | 2.40  |       | 2.70  | 0.094 |       | 0.106 |
| e1                     | 4.95  |       | 5.15  | 0.194 |       | 0.202 |
| F                      | 1.23  |       | 1.32  | 0.048 |       | 0.052 |
| H1                     | 6.20  |       | 6.60  | 0.244 |       | 0.256 |
| J1                     | 2.40  |       | 2.72  | 0.094 |       | 0.107 |
| L                      | 13    |       | 14    | 0.511 |       | 0.551 |
| L1                     | 3.50  |       | 3.93  | 0.137 |       | 0.154 |
| L20                    |       | 16.40 |       |       | 0.645 |       |
| L30                    |       | 28.90 |       |       | 1.137 |       |
| øP                     | 3.75  |       | 3.85  | 0.147 |       | 0.151 |
| Q                      | 2.65  |       | 2.95  | 0.104 |       | 0.116 |



TO-251 (IPAK) MECHANICAL DATA

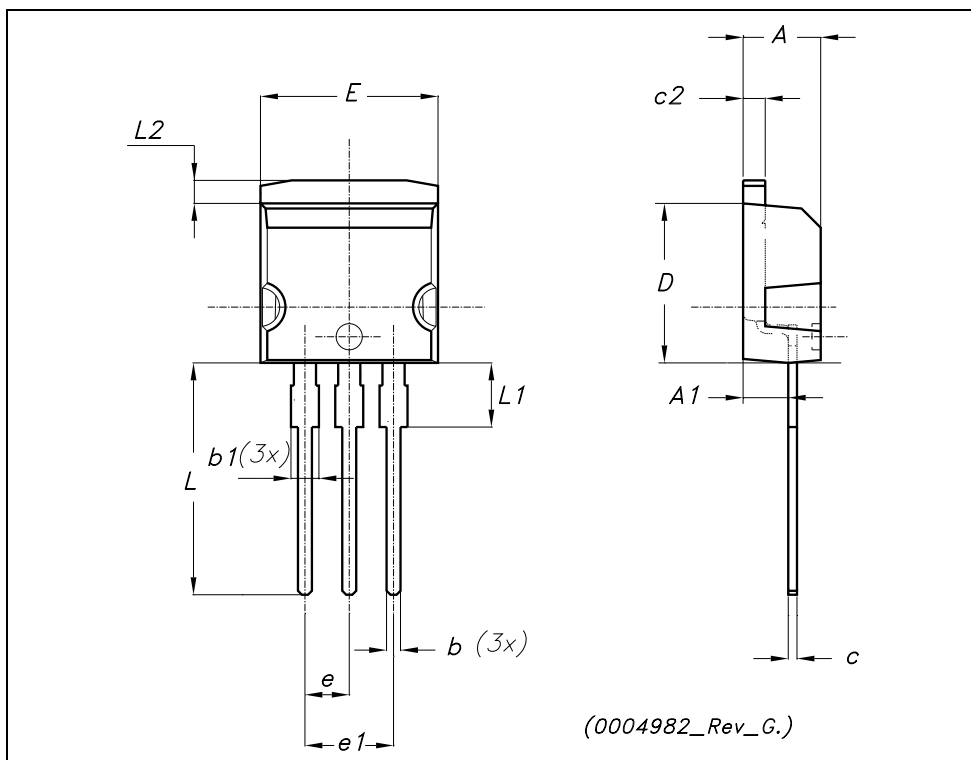
| DIM. | mm   |      |      | inch  |       |       |
|------|------|------|------|-------|-------|-------|
|      | MIN. | TYP. | MAX. | MIN.  | TYP.  | MAX.  |
| A    | 2.2  |      | 2.4  | 0.086 |       | 0.094 |
| A1   | 0.9  |      | 1.1  | 0.035 |       | 0.043 |
| A3   | 0.7  |      | 1.3  | 0.027 |       | 0.051 |
| B    | 0.64 |      | 0.9  | 0.025 |       | 0.031 |
| B2   | 5.2  |      | 5.4  | 0.204 |       | 0.212 |
| B3   |      |      | 0.85 |       |       | 0.033 |
| B5   |      | 0.3  |      |       | 0.012 |       |
| B6   |      |      | 0.95 |       |       | 0.037 |
| C    | 0.45 |      | 0.6  | 0.017 |       | 0.023 |
| C2   | 0.48 |      | 0.6  | 0.019 |       | 0.023 |
| D    | 6    |      | 6.2  | 0.236 |       | 0.244 |
| E    | 6.4  |      | 6.6  | 0.252 |       | 0.260 |
| G    | 4.4  |      | 4.6  | 0.173 |       | 0.181 |
| H    | 15.9 |      | 16.3 | 0.626 |       | 0.641 |
| L    | 9    |      | 9.4  | 0.354 |       | 0.370 |
| L1   | 0.8  |      | 1.2  | 0.031 |       | 0.047 |
| L2   |      | 0.8  | 1    |       | 0.031 | 0.039 |



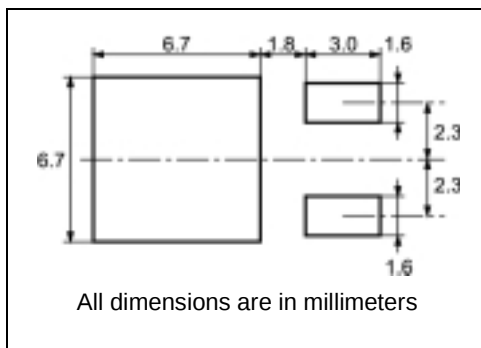
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TO-262 (I<sup>2</sup>PAK) MECHANICAL DATA

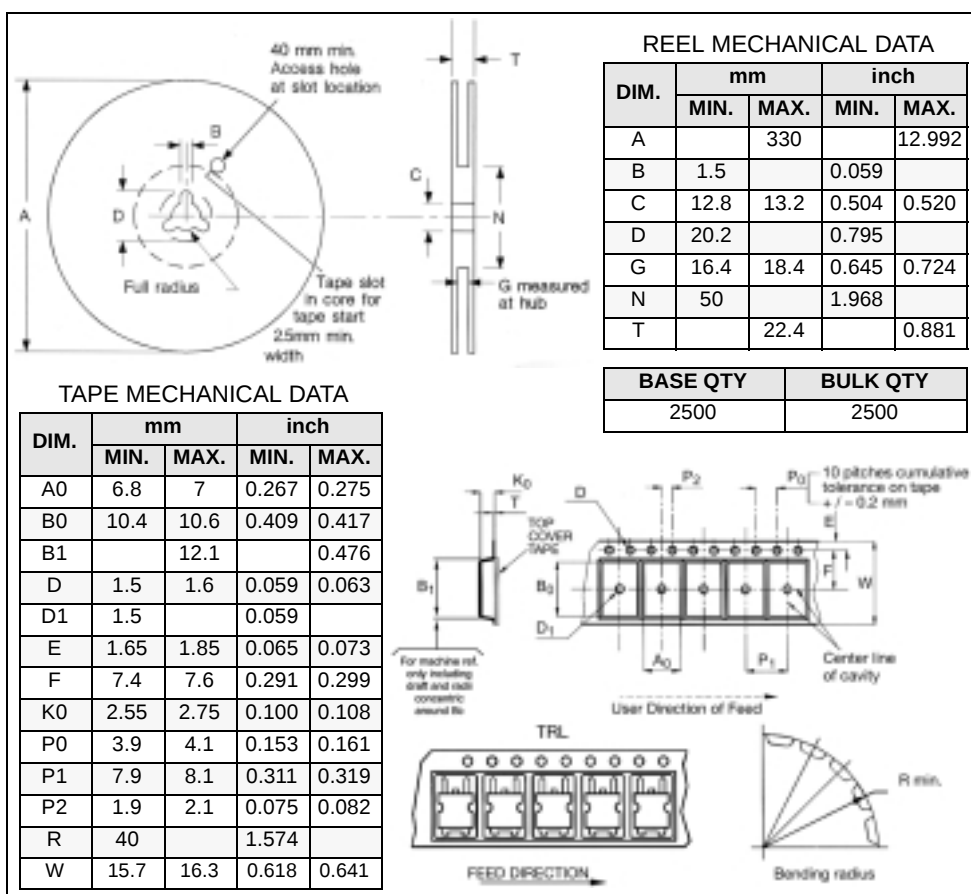
| DIM. | mm.  |      |       | inch  |      |       |
|------|------|------|-------|-------|------|-------|
|      | MIN. | TYP. | MAX.  | MIN.  | TYP. | MAX.  |
| A    | 4.40 |      | 4.60  | 0.173 |      | 0.181 |
| A1   | 2.40 |      | 2.72  | 0.094 |      | 0.107 |
| b    | 0.61 |      | 0.88  | 0.024 |      | 0.034 |
| b1   | 1.14 |      | 1.70  | 0.044 |      | 0.066 |
| c    | 0.49 |      | 0.70  | 0.019 |      | 0.027 |
| c2   | 1.23 |      | 1.32  | 0.048 |      | 0.052 |
| D    | 8.95 |      | 9.35  | 0.352 |      | 0.368 |
| e    | 2.40 |      | 2.70  | 0.094 |      | 0.106 |
| e1   | 4.95 |      | 5.15  | 0.194 |      | 0.202 |
| E    | 10   |      | 10.40 | 0.393 |      | 0.410 |
| L    | 13   |      | 14    | 0.511 |      | 0.551 |
| L1   | 3.50 |      | 3.93  | 0.137 |      | 0.154 |
| L2   | 1.27 |      | 1.40  | 0.050 |      | 0.055 |



## DPAK FOOTPRINT

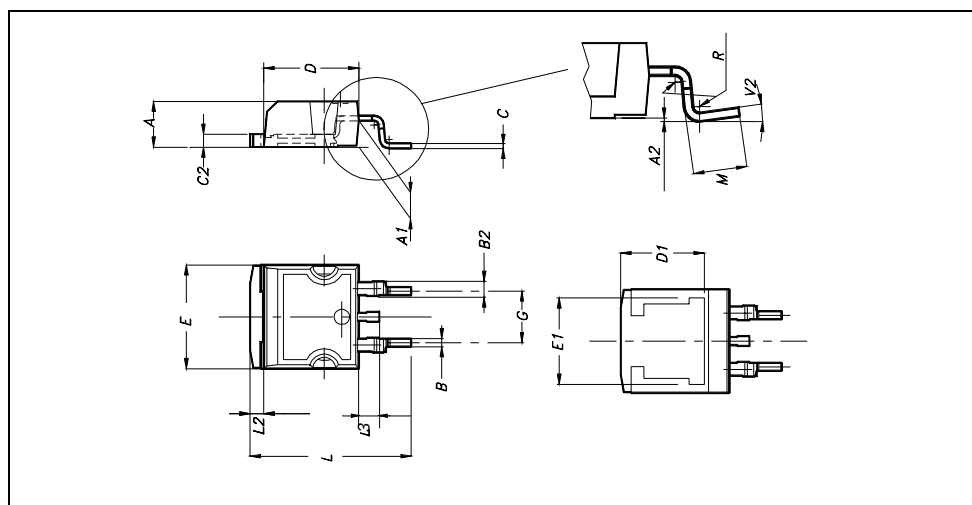


## TAPE AND REEL SHIPMENT



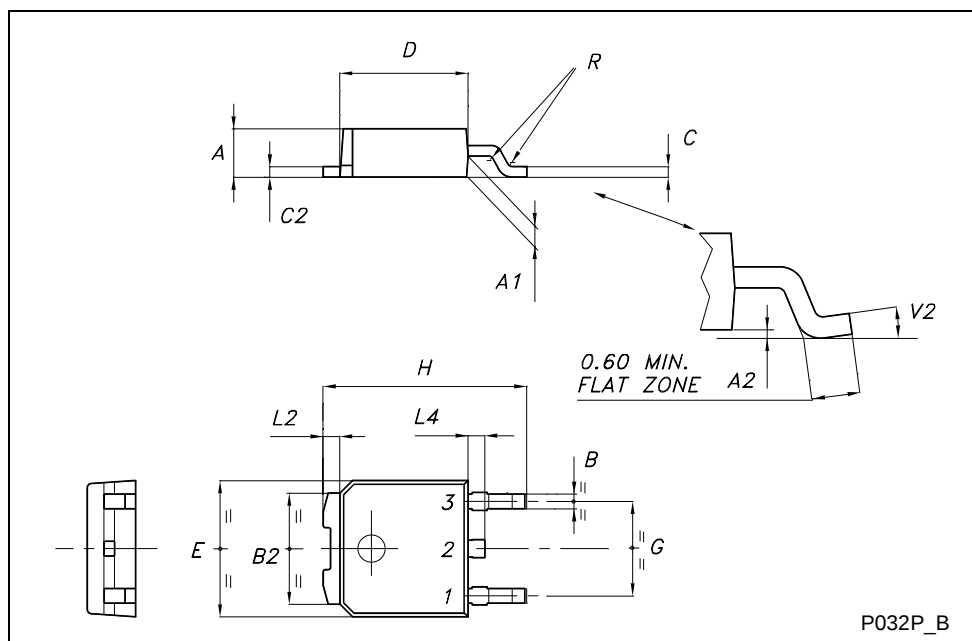
D<sup>2</sup>PAK MECHANICAL DATA

| DIM. | mm.  |      |       | inch  |       |       |
|------|------|------|-------|-------|-------|-------|
|      | MIN. | TYP. | MAX.  | MIN.  | TYP.  | MAX.  |
| A    | 4.4  |      | 4.6   | 0.173 |       | 0.181 |
| A1   | 2.49 |      | 2.69  | 0.098 |       | 0.106 |
| A2   | 0.03 |      | 0.23  | 0.001 |       | 0.009 |
| B    | 0.7  |      | 0.93  | 0.027 |       | 0.036 |
| B2   | 1.14 |      | 1.7   | 0.044 |       | 0.067 |
| C    | 0.45 |      | 0.6   | 0.017 |       | 0.023 |
| C2   | 1.23 |      | 1.36  | 0.048 |       | 0.053 |
| D    | 8.95 |      | 9.35  | 0.352 |       | 0.368 |
| D1   |      | 8    |       |       | 0.315 |       |
| E    | 10   |      | 10.4  | 0.393 |       |       |
| E1   |      | 8.5  |       |       | 0.334 |       |
| G    | 4.88 |      | 5.28  | 0.192 |       | 0.208 |
| L    | 15   |      | 15.85 | 0.590 |       | 0.625 |
| L2   | 1.27 |      | 1.4   | 0.050 |       | 0.055 |
| L3   | 1.4  |      | 1.75  | 0.055 |       | 0.068 |
| M    | 2.4  |      | 3.2   | 0.094 |       | 0.126 |
| R    |      | 0.4  |       |       | 0.015 |       |
| V2   | 0°   |      | 4°    |       |       |       |



## TO-252 (DPAK) MECHANICAL DATA

| DIM. | mm   |      |       | inch  |       |       |
|------|------|------|-------|-------|-------|-------|
|      | MIN. | TYP. | MAX.  | MIN.  | TYP.  | MAX.  |
| A    | 2.20 |      | 2.40  | 0.087 |       | 0.094 |
| A1   | 0.90 |      | 1.10  | 0.035 |       | 0.043 |
| A2   | 0.03 |      | 0.23  | 0.001 |       | 0.009 |
| B    | 0.64 |      | 0.90  | 0.025 |       | 0.035 |
| B2   | 5.20 |      | 5.40  | 0.204 |       | 0.213 |
| C    | 0.45 |      | 0.60  | 0.018 |       | 0.024 |
| C2   | 0.48 |      | 0.60  | 0.019 |       | 0.024 |
| D    | 6.00 |      | 6.20  | 0.236 |       | 0.244 |
| E    | 6.40 |      | 6.60  | 0.252 |       | 0.260 |
| G    | 4.40 |      | 4.60  | 0.173 |       | 0.181 |
| H    | 9.35 |      | 10.10 | 0.368 |       | 0.398 |
| L2   |      | 0.8  |       |       | 0.031 |       |
| L4   | 0.60 |      | 1.00  | 0.024 |       | 0.039 |
| V2   | 0°   |      | 8°    | 0°    |       | 0°    |



**Table 10: Revision History**

| <b>Date</b> | <b>Revision</b> | <b>Description of Changes</b>                |
|-------------|-----------------|----------------------------------------------|
| 16-Jun-2004 | 1               | D <sup>2</sup> PAK Included. New Stylesheet. |
| 06-Sep-2005 | 2               | Inserted Ecopack indication                  |

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